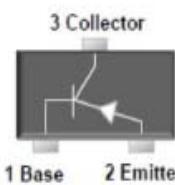


Small Signal Product

350mW, PNP Small Signal Transistor

FEATURES

- Epitaxial planar die construction
- Surface device type mounting
- Moisture sensitivity level 1
- Matte Tin (Sn) lead finish with Nickel (Ni) underplate
- Pb free version and RoHS compliant
- Packing code with suffix "G" means green compound (halogen-free)


SOT-23


MECHANICAL DATA

- Case: SOT- 23, molded plastic
- Terminal: Matte tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- High temperature soldering guaranteed: 260°C/10s
- Weight: 8 mg (approximately)
- Marking Code: 3E.

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	VALUE	UNIT
Power Dissipation	P_D	350	mW
Collector-Base Voltage	V_{CBO}	-40	V
Collector-Emitter Voltage	V_{CEO}	-40	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-200	mA
Thermal Resistance Junction-Ambient	$R_{\theta JA}$	357	°C/W
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to + 150	°C

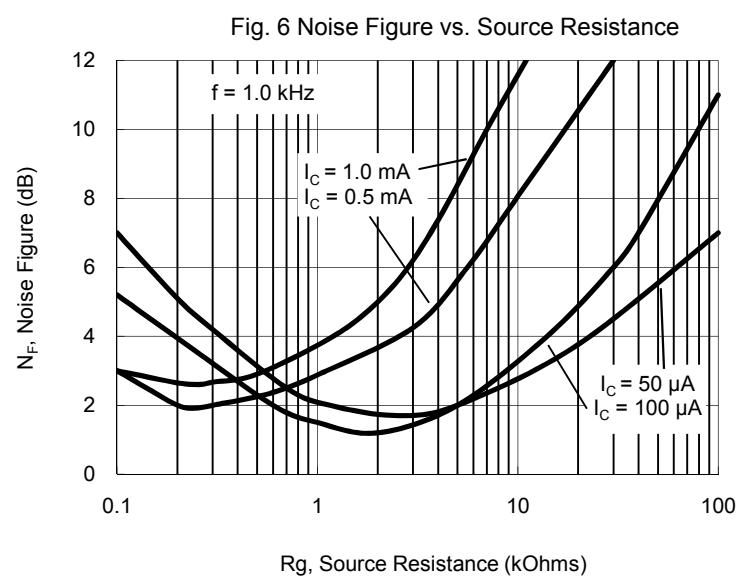
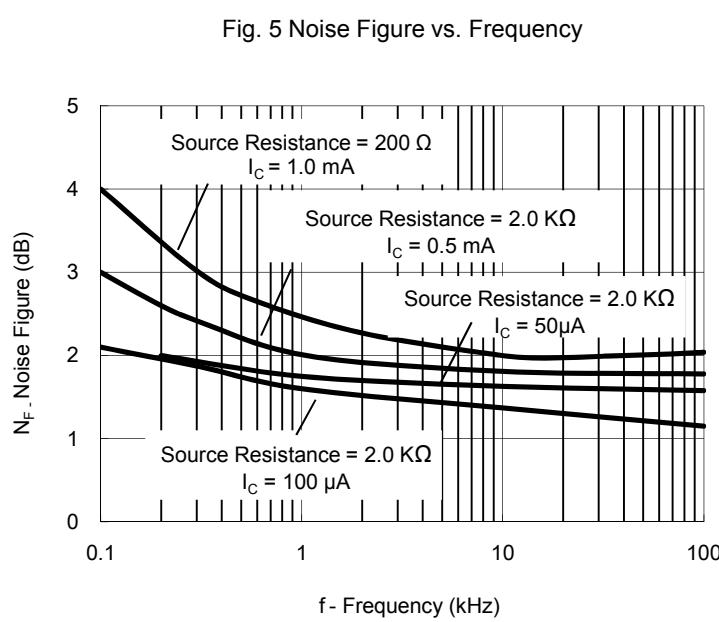
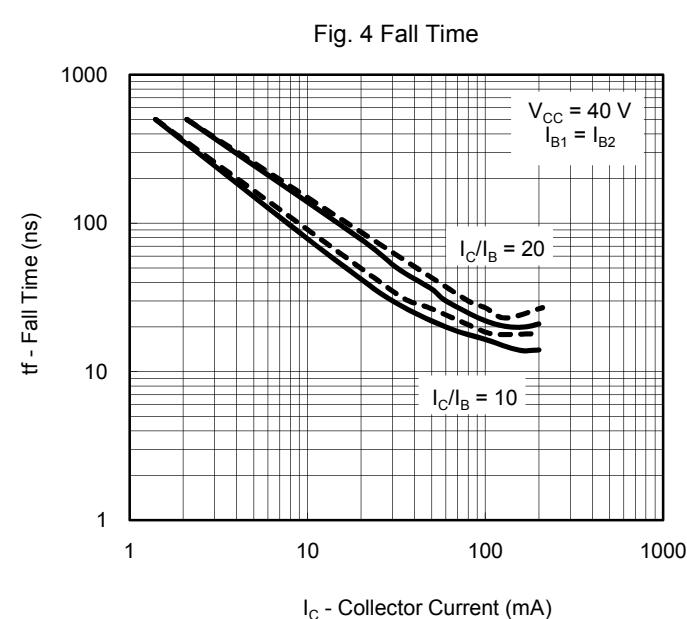
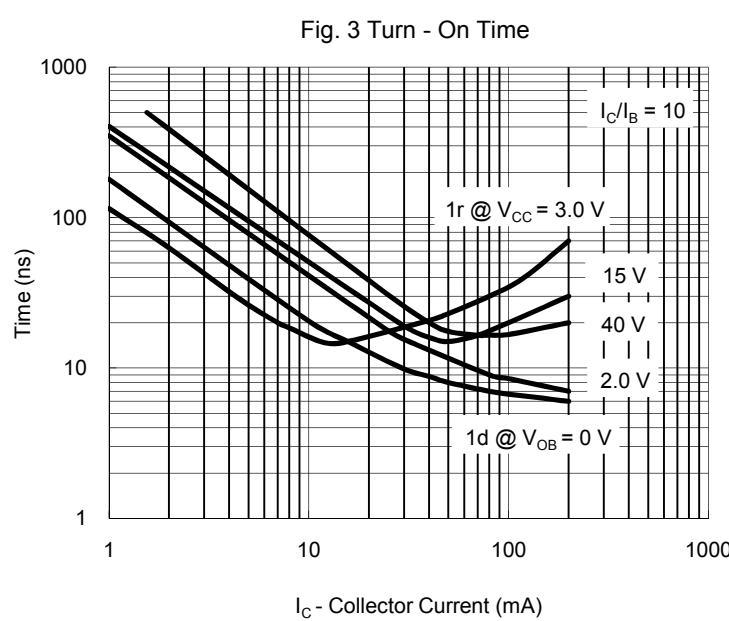
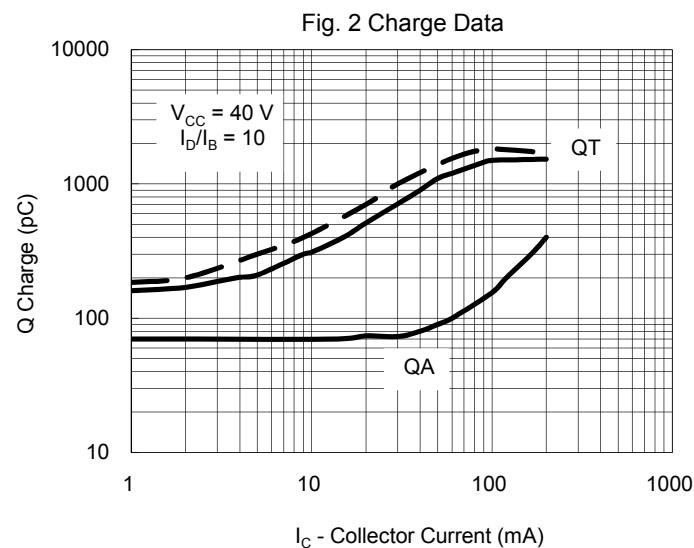
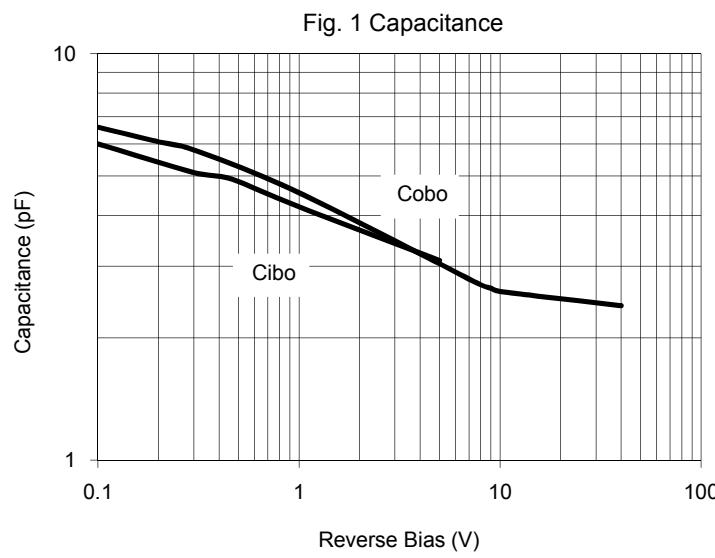
Notes:1. Valid provided that electrodes are kept at ambient temperature

PARAMETER	SYMBOL	MIN	MAX	UNIT
Collector-Base Breakdown Voltage $I_C = 10 \mu\text{A}$ $I_E = 0$	$V_{(BR)CBO}$	-40	-	V
Collector-Emitter Breakdown Voltage $I_C = -1 \text{ mA}$ $I_B = 0$	$V_{(BR)CEO}$	-40	-	V
Emitter-Base Breakdown Voltage $I_E = -10 \mu\text{A}$ $I_C = 0$	$V_{(BR)EBO}$	-5	-	V
Collector Base Cut-off Current $V_{CB} = -40 \text{ V}$	I_{CBO}	-	-100	nA
Emitter Base Cut-off Current $V_{EB} = -6 \text{ V}$	I_{EBO}	-	-50	nA
DC Current Gain	h_{FE}	60	300	
		80		
		100		
		60		
		30		
Collector-Emitter Saturation Voltage $I_C = -10 \text{ mA}$ $I_B = -1 \text{ mA}$	$V_{CE(sat)}$	-	-0.25	V
		-	-0.4	
Base-Emitter Saturation Voltage $I_C = -10 \text{ mA}$ $I_B = -1 \text{ mA}$	$V_{BE(sat)}$	-0.65	-0.85	V
		-	-0.95	
Gain-Bandwidth Product $V_{CE} = -20 \text{ V}$ $I_C = -10 \text{ mA}$ $f = 100\text{MHz}$	f_T	250	-	MHz
Output Capacitance $V_{CB} = -5 \text{ V}$ $I_E = 0$ $f = 1\text{MHz}$	C_{obo}	-	4.5	pF
Delay time $V_{CC} = -3 \text{ V}$ $V_{BE} = -0.5 \text{ V}$ $I_C = -10 \text{ mA}$	t_d	-	35	ns
Rise time $I_{B1} = -1.0 \text{ mA}$	t_r	-	35	ns
Storage time $V_{CC} = -3 \text{ V}$ $I_C = -10 \text{ mA}$	t_s	-	225	ns
Fall time $I_{B1} = I_{B2} = -1.0 \text{ mA}$	t_f	-	75	ns

Small Signal Product

RATINGS AND CHARACTERISTICS CURVES

($T_A=25^\circ\text{C}$ unless otherwise noted)



Small Signal Product

h Parameters ($V_{CE} = -10$ V_{DC} , $f = 1.0$ kHz , $T_A = 25$ °C)

Fig. 7 Current Gain

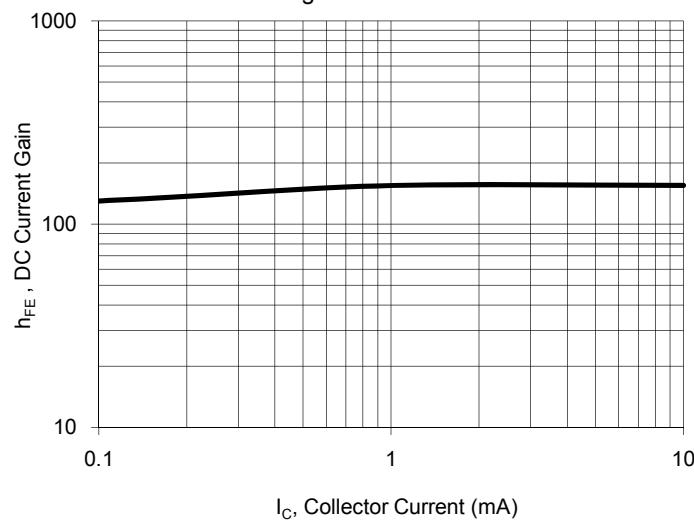


Fig. 8 Output Admittance

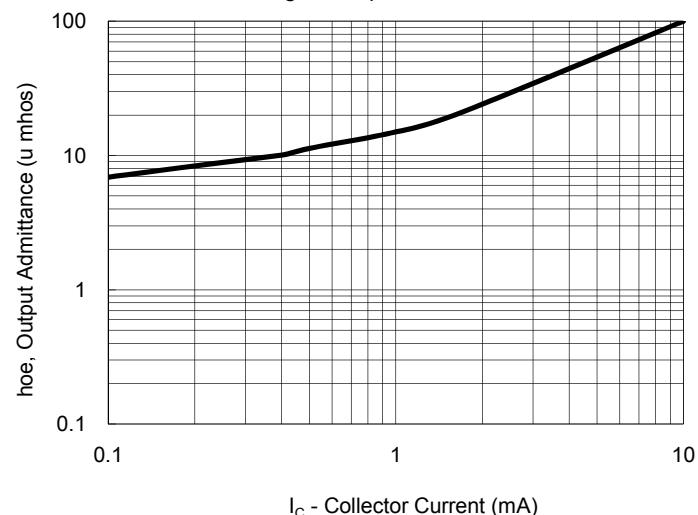


Fig. 9 Input Impedance

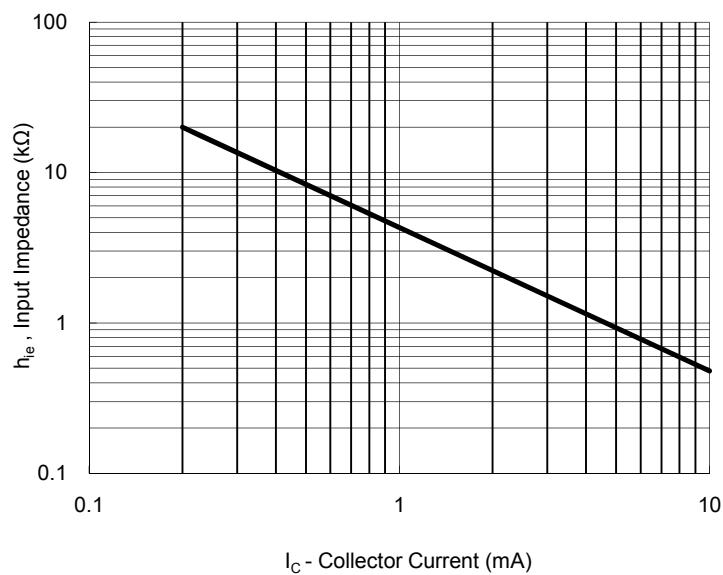


Fig. 10 Voltage Feedback Ratio

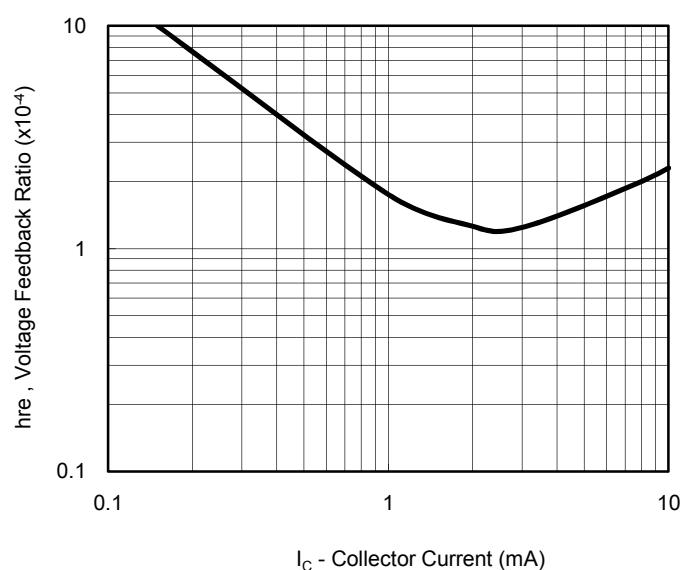


Fig. 11 "ON" Voltages

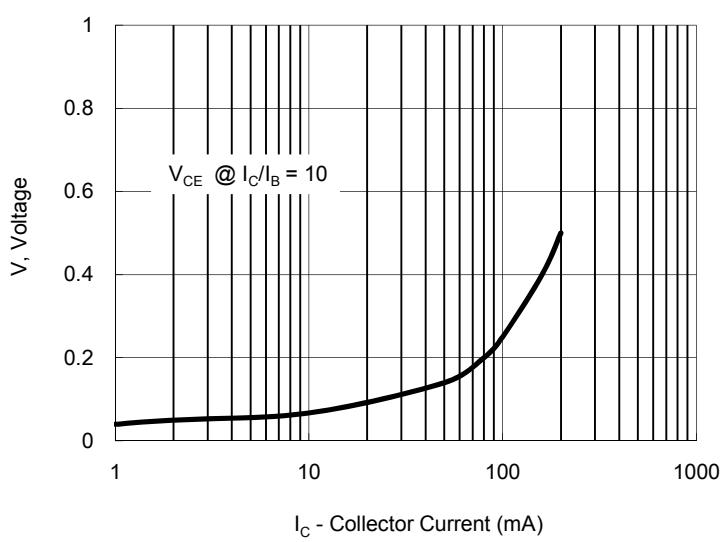
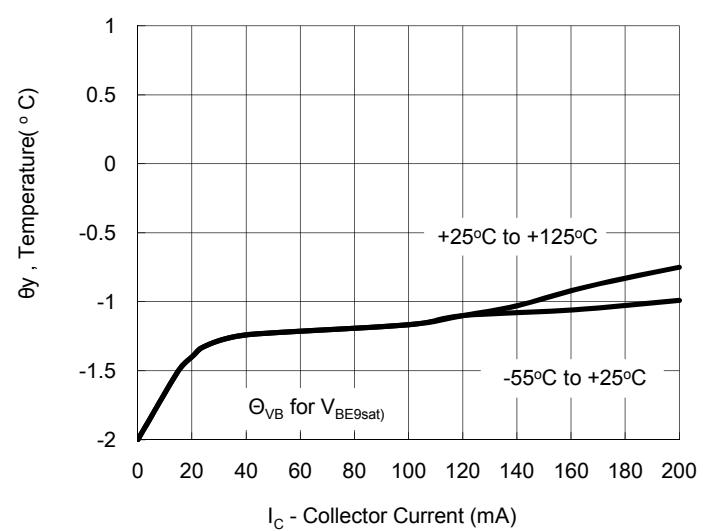


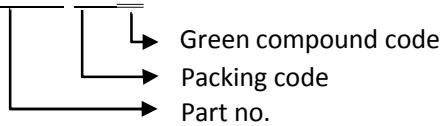
Fig. 12 Temperature Coefficients



Small Signal Product

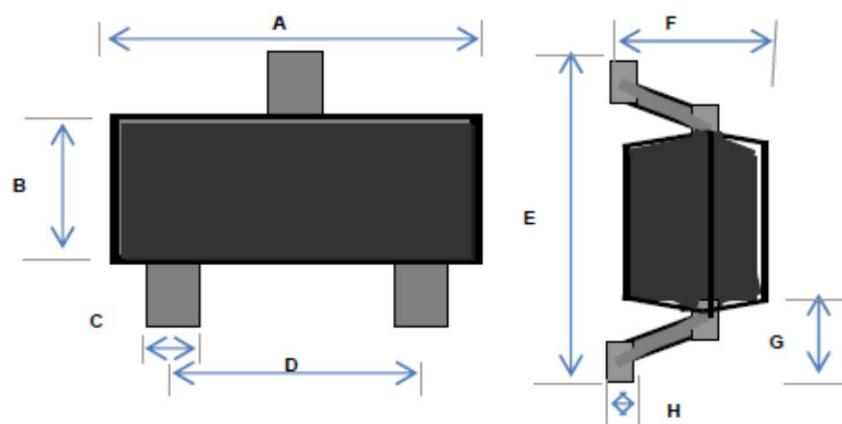
ORDER INFORMATION (EXAMPLE)

MMBT3906L RFG



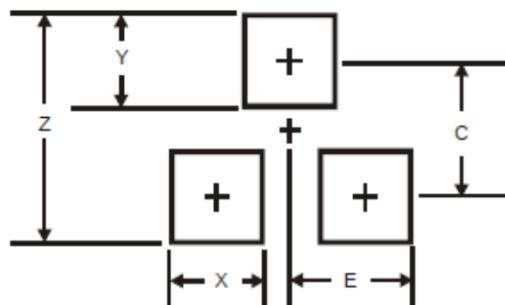
PACKAGE OUTLINE DIMENSIONS

SOT-23



DIM.	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	2.70	3.10	0.106	0.122
B	1.10	1.50	0.043	0.059
C	0.30	0.51	0.012	0.020
D	1.78	2.04	0.070	0.080
E	2.10	2.64	0.083	0.104
F	0.89	1.30	0.035	0.051
G	0.55 REF		0.022 REF	
H	0.10 REF		0.004 REF	

SUGGEST PAD LAYOUT



DIM.	Unit (mm)		Unit (inch)	
	TYP	TYP	TYP	TYP
Z	2.90		0.114	
X	0.80		0.031	
Y	0.90		0.035	
C	2.00		0.079	
E	1.35		0.053	

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by Taiwan Semiconductor manufacturer:

Other Similar products are found below :

[619691C](#) [MCH4017-TL-H](#) [BC546/116](#) [BC557/116](#) [BSW67A](#) [NTE158](#) [NTE187A](#) [NTE195A](#) [NTE2302](#) [NTE2330](#) [NTE63](#) [C4460](#)
[2SA1419T-TD-H](#) [2SA1721-O\(TE85L,F\)](#) [2SA2126-E](#) [2SB1204S-TL-E](#) [2SD2150T100R](#) [SP000011176](#) [FMMTA92QTA](#) [2N2369ADCSM](#)
[2N5769](#) [2SC2412KT146S](#) [2SC5490A-TL-H](#) [2SD1816S-TL-E](#) [2SD1816T-TL-E](#) [CMXT2207 TR](#) [CPH6501-TL-E](#) [MCH4021-TL-E](#)
[US6T6TR](#) [NJL0281DG](#) [732314D](#) [CMXT3906 TR](#) [CPH3121-TL-E](#) [CPH6021-TL-H](#) [873787E](#) [IMZ2AT108](#) [UMX21NTR](#) [MCH6102-TL-E](#)
[FP204-TL-E](#) [NJP0302DG](#) [2N3583](#) [2SA1434-TB-E](#) [2SC3143-4-TB-E](#) [2SD1621S-TD-E](#) [NTE103](#) [30A02MH-TL-E](#) [NSV40301MZ4T1G](#)
[NTE101](#) [NTE13](#) [NTE15](#)